

AGBSFXXX

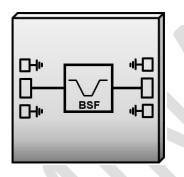
GaAs IPD MMIC Bandstop Filter Series

Typical Applications

- Communication Systems
- Point to Point Radio
- Fiber Optics
- Test Equipment
- Wideband Military & Space

Series Features

- Ka-Band bandstop filter
- 50Ω Matched DC coupled RF Ports
- Chip Size: 1.00 x 0.75 x 0.1 mm; Matches AGATNxx, AGLPFxxx, AGBPFxxx, and AGTRMxxx series MMICs



AGBSFxxx Series Parts

Part Number	Description	Page No.
AGBSF295	27GHz – 32GHz Bandstop Filter	2

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AGBSF295

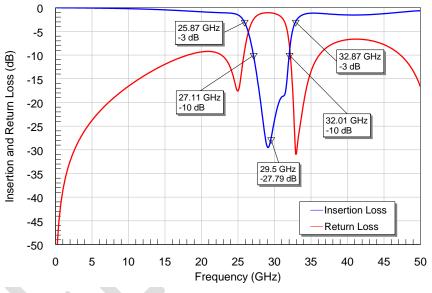
GaAs IPD MMIC 27GHz - 32GHz Bandstop Filter

Features

- Center Frequency: 29.5GHz
- Stopband Rejection: 27.8dB @ 29.5GHz
- Passband loss: 3dB at 25.9GHz and 32.9GHz
- 50Ω Matched DC coupled RF Ports

Performance Graphs

Insertion and Return Loss (Simulated)



Electrical Specifications (TA = +25°C)

Parameter	Units	Minimum	Typical	Maximum
Frequency	GHz	27.1		32.0
Stopband Rejection	dB	10.0		29.5
Passband 3dB Point	GHz	25.9		32.9
Passband Return Loss	dB	6.6	12	
Package Type			Die	

pical	Maximum
	32.0
	29.5

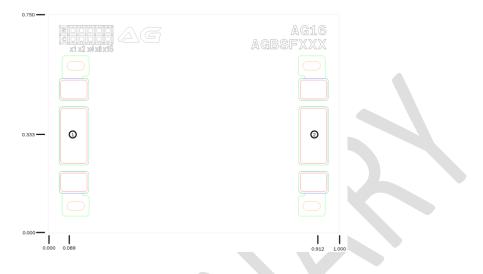
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Outline Drawing (dimensions in mm)



Pad Descriptions

Γ	Pad	Function	Pad Size	Description
	1	RFIN	101x200µm	DC coupled 50Ω Matched
	2	RFOUT	101x200µm	DC coupled 50Ω Matched
	Die Bottom	GND	Backside	Epoxy/Solder to Baseplate

Absolute Maximum Ratings

Parameter	Rating
Drain Bias Voltage (VDD)	No Bias
RF Input Power (RFIN)	+20dBm*
Channel Temperature	150°C
Storage Temperature	-65 to 150°C
Operating Temperature	-55 to 85°C
*To be tested	

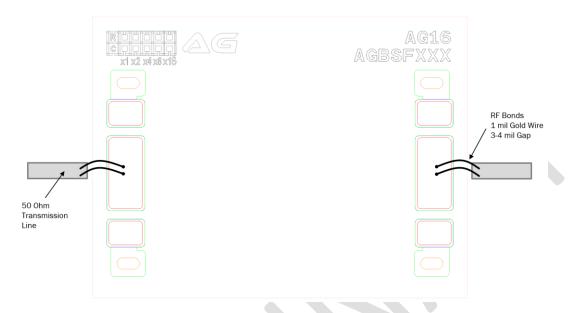
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Assembly Diagrams



Assembly Notes:

- 1. Die Thickness is 100µm
- 2. Bondpad metallization: $7\mu m$ gold
- 3. Backside metallization: $4.5 \mu m$ gold
- 4. Silver Epoxy or AuSn Eutectic attach MMIC

Die Packaging Information

• GP-4 (Gel-Pak)



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